

10/766249

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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Stephen M. Gates, et al.

Docket: 16876Z

Patent No: 6,958,526

Dated: March 08, 2006

Issued: October 25, 2005

For: ELECTRONIC STRUCTURES WITH

REDUCED CAPACITANCE

Certificate
MAR 1 7 2006
of Correction

Commissioner of Patents P.O. Box 1450 Alexandria, VA 22313-1450

REQUEST FOR CERTIFICATE OF CORRECTION

Sir:

It appearing that errors have been introduced in the course of printing the Patent issued in the above application, it is respectfully requested that the Commissioner issue a Certificate of Correction in the following respects:

Column 1, Line 45-46:

"Prior art inductor structures used in RF and microwave circuits are commonly isolated from ground using SiO_2 which has a dielectric constant (k) of 4 to 4.2. Prior art inductors maybe passivated with a polymer dielectric (e.g. Polyimide which has a dielectric constant (k) or about 2.9"

should read

-- Prior art inductor structures used in RF and microwave circuits are commonly isolated from ground using SiO₂ which has a dielectric constant (k) of 4 to 4.2. Prior art inductors may be passivated with a polymer dielectric (e.g. Polyimide) which has a dielectric constant (k) of about 2.9. --

Column 1, Line 66:

"RE" should read -- RF --

Column 11, Line 26, Claim 4:

"surf ice" should read -- surface --

Column 11, Line 40, Claim 7:

"The electronic Structure of " should read -- The electronic structure of --

Column 12, Line 24, Claim 16:

"containing lees C" should read -- containing less than C --

It is further noted that additional errors typographical in nature are incorporated into the printed specification, but are believed to be satisfactorily clear the context and accordingly it is simply requested that this paper be made of record in the file for such clarification as may be appropriate. They are as follows:

Column 8, Line 61:

"reference to to Example" should read -- reference to Example 1. --

Abstract, Line 6: [57]

"curent" should read -- current --

Respectfully submitted,

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Reg. No. 39,394

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UNITED STATES PATENT AND TRADEMARK OFFICE CERTIFICATE OF CORRECTION

PATENT NO : 6,958,526

APPLICATION NO: 10/766,249

ISSUE DATE : October 25, 2005

INVENTOR(S) : Stephen M. Gates, et al.

It is certified that an error appears or errors appear in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

Column 1, Line 45-46:

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